EMF23XV6T5

Dual Transistor - Power Management

NPN/PNP Dual (Complementary)

Features

- Low $V_{CE(SAT)}$, < 0.5 V
- These are Pb-Free Devices

MAXIMUM RATINGS

Q

| Rating | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 50 | Vdc |
| Collector-Emitter Voltage | V _{CEO} | 50 | Vdc |
| Collector Current | Ic | 100 | mAdc |

Q2

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector - Emitter Voltage | V _{CEO} | -60 | V |
| Collector - Base Voltage | V _{CBO} | -50 | V |
| Emitter - Base Voltage | V _{EBO} | -6.0 | V |
| Collector Current - Continuous | I _C | -100 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic (One Junction Heated) | Symbol | Max | Unit |
|---|-----------------------|-----------------------------|-------------------|
| Total Device Dissipation T _A = 25°C | P_{D} | 357 | mW |
| Derate above 25°C | | (Note 1) 2.9 (Note 1) | mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{	heta JA}$ | 350 (Note 1) | °C/W |
| Characteristic | | | |
| | | | |
| (Both Junctions Heated) | Symbol | Max | Unit |
| (Both Junctions Heated) Total Device Dissipation $T_A = 25^{\circ}C$ | Symbol P _D | 500 | Unit mW |
| , | | | |
| Total Device Dissipation T _A = 25°C | | 500 (Note 1) 4.0 | mW |

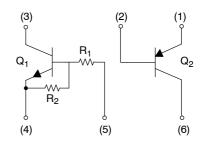
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad.



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SOT-563 CASE 463A STYLE 1

MARKING DIAGRAM



UW = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|----------------------|-----------------------|
| EMF23XV6T5 | SOT-563 (Pb-Free) | 8000/Tape & Reel |
| EMF23XV6T5G | SOT-563 (Pb-Free) | 8000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

EMF23XV6T5

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|----------------------|------|-----|------|------|
| Q1: NPN | | | | | |
| Collector-Base Cutoff Current (V _{CB} = 50 V, I _E = 0) | I _{CBO} | - | - | 100 | nAdc |
| Collector-Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0) | I _{CEO} | - | _ | 500 | nAdc |
| Emitter-Base Cutoff Current ($V_{EB} = 6.0 \text{ V}, I_{C} = 0$) | I _{EBO} | - | _ | 0.5 | mAdc |
| Collector-Base Breakdown Voltage ($I_C = 10 \mu A, I_E = 0$) | V _{(BR)CBO} | 50 | _ | - | Vdc |
| Collector-Emitter Breakdown Voltage (Note 3) ($I_C = 2.0$ mA, $I_B = 0$) | V _{(BR)CEO} | 50 | _ | - | Vdc |
| DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA) | h _{FE} | 35 | 60 | - | - |
| Collector-Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.3 mA) | V _{CE(sat)} | - | - | 0.25 | Vdc |
| Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 k Ω) | V _{OL} | - | - | 0.2 | Vdc |
| Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.5 V, R _L = 1.0 k Ω) | V _{OH} | 4.9 | - | - | Vdc |
| Input Resistor | R1 | 7.0 | 10 | 13 | kΩ |
| Resistor Ratio | R1/R2 | 0.8 | 1.0 | 1.2 | - |
| Q2: PNP | | | | | |
| Collector–Base Breakdown Voltage ($I_C = -50 \mu Adc, I_E = 0$) | V _{(BR)CBO} | -60 | - | - | Vdc |
| Collector–Emitter Breakdown Voltage (I _C = -1.0 mAdc, I _B = 0) | V _{(BR)CEO} | -50 | - | - | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = -50 \mu Adc$, $I_E = 0$) | V _{(BR)EBO} | -6.0 | - | - | Vdc |
| Collector-Base Cutoff Current (V _{CB} = -30 Vdc, I _E = 0) | I _{CBO} | - | - | -0.5 | nA |
| Emitter-Base Cutoff Current (V _{EB} = -5.0 Vdc, I _B = 0) | I _{EBO} | - | _ | -0.5 | μΑ |
| Collector–Emitter Saturation Voltage (Note 3) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc) | V _{CE(sat)} | _ | - | -0.5 | Vdc |
| DC Current Gain (Note 3) (V _{CE} = -6.0 Vdc, I _C = -1.0 mAdc) | h _{FE} | 120 | - | 560 | - |
| Transition Frequency (V _{CE} = -12 Vdc, I _C = -2.0 mAdc, f = 30 MHz) | f _T | - | 140 | - | MHz |
| Output Capacitance (V _{CB} = -12 Vdc, I _E = 0 Adc, f = 1.0 MHz) | C _{OB} | - | 3.5 | - | pF |

^{2.} Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint. 3. Pulse Test: Pulse Width \leq 300 μ s, DC \leq 2%.

TYPICAL ELECTRICAL CHARACTERISTICS — Q1, NPN

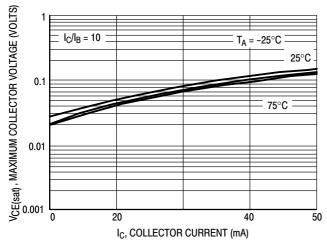


Figure 1. V_{CE(sat)} versus I_C

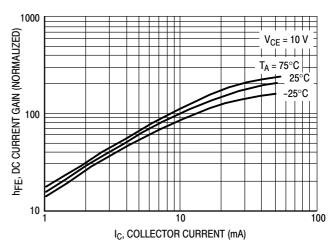


Figure 2. DC Current Gain

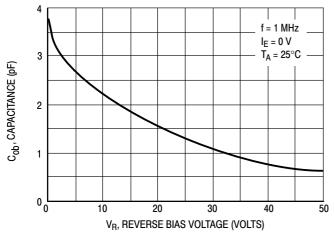


Figure 3. Output Capacitance

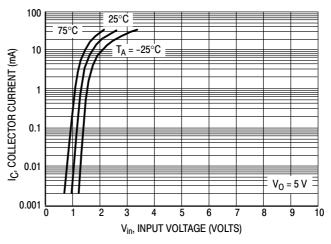


Figure 4. Output Current versus Input Voltage

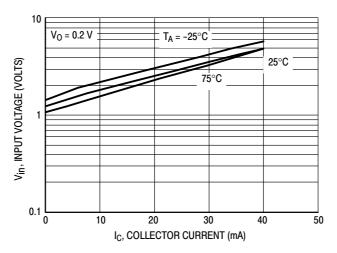
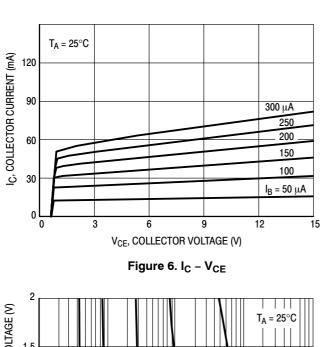


Figure 5. Input Voltage versus Output Current

EMF23XV6T5

TYPICAL ELECTRICAL CHARACTERISTICS - Q2, PNP



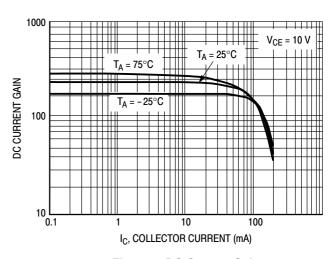
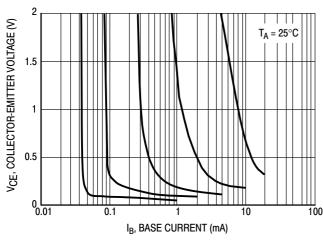


Figure 7. DC Current Gain



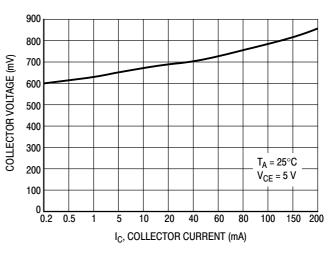
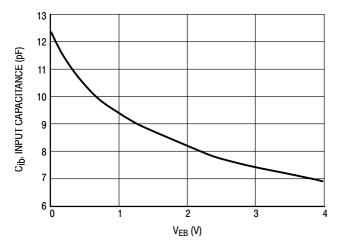


Figure 8. Collector Saturation Region

Figure 9. On Voltage



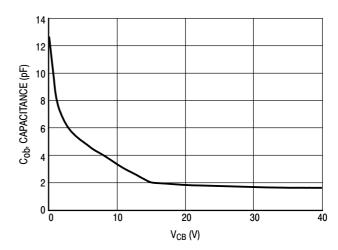


Figure 10. Capacitance

Figure 11. Capacitance

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



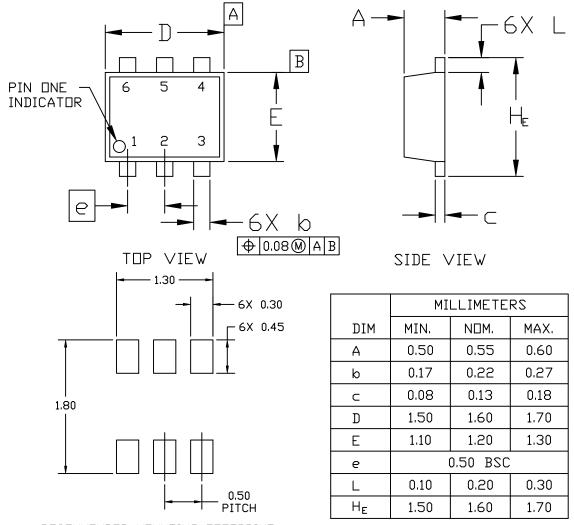


SOT-563, 6 LEAD CASE 463A ISSUE H

DATE 26 JAN 2021

NOTES:

- I. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



RECOMMENDED MOUNTING FOOTPRINT*

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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SOT-563, 6 LEAD

CASE 463A ISSUE H

2

1

DATE 26 JAN 2021

| STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1 | STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1 | STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE |
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| STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR | STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE 4. ANODE 5. CATHODE 6. CATHODE | STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE |
| STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE | STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN | STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2 5. GATE 2 6. DRAIN 1 |
| STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2 5. N/C 6. ANODE 1 | STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | |

GENERIC MARKING DIAGRAM*



XX = Specific Device CodeM = Month Code= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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